What lurks below the last plateau

15+ years of 0.7: What have we learned and where to next?



<u>Lecture 4</u>: Bound-states and electron organization in QPCs

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- There are two areas of significant debate when it comes to Kondo and QPCs:
 - 1. Does the data really behave like you'd expect it to for Kondo? Yesterday
 - 2. Is there really a bound-state inside a QPC? Today





Let's start again with spin DFT



K. Hirose et al., PRL 90, 026804 (2003).



SDFT: Bound-states or not?



Note added in proof: Recently, Y. Meir, K. Hirose, and N.S. Wingreen have reported on a Kondo model for the "0.7 anomaly" (cond-mat/0207044). As in our work these authors also find local magnetization in the QPC using the Kohn-Sham equations. However, we do not recover their quasibound states, which might depend on different geometries.

K.-F. Berggren & I.I. Yakimenko, PRB <u>66</u>, 085323 (2002).



undoped AlGaAs

GaAs



Spin-DFT: Interesting and controversial...



T. Rejec & Y. Meir, Nature <u>442</u>, 900 (2006).





Spin-DFT: Bound-states or not?



T. Rejec & Y. Meir, Nature <u>442</u>, 900 (2006).

Bound state for \uparrow but not \downarrow

"We have not found any indication of such [bound] states..."

K.-F. Berggren et al., JPCM 20, 164203 (2008).

"The features of the evolution and formation of the localized spin-polarized quasi-bound states in the QPC agree well with the results reported by Hirose et al and Rejec and Meir."

I.V. Zozoulenko *et al.*, JPCM <u>20</u>, 164217 (2008).

"The feature we have found can be best described as weakly bound."

R. Akis & D.K. Ferry, JPCM 20, 164201 (2008).







What other evidence do we have for boundstate formation in QPCs?



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Experimental evidence for bound states in QPCs

• To get some insight, we need to go to more complex devices.

Gates 1, 2 and 3 held at –1.2V while gate 4 is swept from 0 to –2V.





∎₩₿₿

(c)

The upper QPC separates reservoirs in top-left and top-right corners, and couples via the side into the quantum dot.

The lower QPC is the dot
opening, and it is
controlled with gate 4.

Rationale: Use the upper QPC as a nonlocal probe of the lower QPC as its driven to pinch-off.

T. Morimoto et al., APL 82, 3952 (2003).

V-





Experimental evidence for bound states in QPCs



T. Morimoto et al., APL 82, 3952 (2003).



Support from Anderson model calculations

• Puller *et al.* use an Anderson Hamiltonian that's a bit more complex than usual.



V.I. Puller et al., PRL <u>92</u>, 096802 (2004).



Support from Anderson model calculations

• The mathematics gets complex (i.e., read the paper) but ultimately, they calculate the conductance for the upper QPC using the Landauer formalism:

$$g = \frac{e^2}{h} \sum_{\sigma} \int d\boldsymbol{\epsilon} [-f'(\boldsymbol{\epsilon})] \Gamma_{\sigma} \rho_{\sigma}(\boldsymbol{\epsilon}).$$

where $f(\varepsilon)$ is the Fermi distribution, Γ_{σ} is the coupling of the upper QPC to its leads and $\rho_{\sigma}(\varepsilon)$ is the density of states per spin in the upper QPC. The coupling via the preceding Hamiltonian affects this density of states, inducing a correction to the upper QPC conductance:

$$g = \bar{g} + \Delta g$$

where:
$$\Delta g = \frac{2e^2}{\hbar} \frac{|T|^2}{4} \sum_{n=0}^{N-1} \frac{1}{E_F - \epsilon_0 - n\hbar\omega_y} \times \sum_{\sigma} \frac{E_F - \epsilon_{\sigma} - U\langle n_{\bar{\sigma}} \rangle}{(E_F - \epsilon_{\sigma} - U\langle n_{\bar{\sigma}} \rangle)^2 + (\Delta_{\sigma} + \pi_{\sigma})^2}$$

If you plot this...

V.I. Puller et al., PRL <u>92</u>, 096802 (2004).





Support from Anderson model calculations

• You get a structure looking much like that seen in the experimental data.



V.I. Puller et al., PRL <u>92</u>, 096802 (2004).



Is the signal in the upper QPC a Fano resonance?

 Follow-up work suggested that the conductance correction is actually a Fano resonance...



L.G. Mourokh et al., Appl. Phys. Lett. 87, 192501 (2005).

 Before considering Fano resonances in QPCs further, let's digress briefly to look at the Fano effect.





The Fano effect

- The Fano effect is named after Ugo Fano, who in 1935 explained the strange highlyasymmetrical lineshapes observed in the optical absorption spectra of noble gases.
- The lineshape occurs when a discrete state in the spectrum interferes with the continuum of states amongst which it resides.



U. Fano, Nuovo Cimento 12, 154 (1935); U. Fano & J.W. Cooper, Phys. Rev. 137, A1364 (1965).



The Fano effect



These lineshapes form a family described by the Fano lineshape formula:

$$\sigma(\varepsilon) = \sigma_{\rm a}[(\boldsymbol{q} + \varepsilon)^2 / (1 + \varepsilon^2)] + \sigma_{\rm b}$$

where $\sigma(\varepsilon)$ is the absorption cross-section for incident photons of energy *E* and $\varepsilon = E$ $-E_r / \frac{1}{2}\Gamma$ is the separation between *E* and a resonance energy E_r due to a discrete autoionizing level in the atom, with Γ being the lifetime broadening of this level.

The prefactors σ_a and σ_b represent the two components of the spectrum corresponding to states in the continuum that do and do not interact with the discrete level.

The last detail is the Fano factor q, which controls the lineshape...

U. Fano & J.W. Cooper, Phys. Rev. <u>137</u>, A1364 (1965).





The Fano effect

• The Fano factor q controls the lineshape, which starts out as a symmetric minima for q = 0, becomes highly asymmetric at q = 1, and becomes the Lorentzian Breit-Wigner lineshape at $q \rightarrow \infty$.



U. Fano, Phys. Rev. <u>124</u>, 1866 (1961).





The important thing about Fano is its...





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Taking Fano into mesoscopic devices...

• At its simplest, all the Fano effect requires is interference between a discrete state and a continuum of states. You don't need atoms for this, you can do it with mesoscopic devices too.



K. Kobayashi *et al.*, PRL <u>88</u>, 256806 (2002).





Taking Fano into mesoscopic devices...



K. Kobayashi *et al*., PRL <u>88</u>, 256806 (2002).



Taking Fano into mesoscopic devices...

• Can also be found in the conductance of a QPC side-coupled to a quantum dot.



• Seems to be ideal for detecting a bound state in two coupled QPCs.

A.C. Johnson et al., PRL <u>93</u>, 106803 (2004).





Y. Yoon et al., PRL <u>99</u>, 136805 (2007).



• The QPC detects a bound-state in a second QPC in the same way that it detects a deliberately coupled quantum dot.



Y. Yoon *et al*., PRB <u>79</u>, 121304 (2009).





 If you cut off the connection between the detector and the swept QPC, then the Fano resonances go away.



Y. Yoon et al., PRB 79, 121304 (2009).





 If you change the separation between the detector and swept QPC, then the Fano factor changes, with q becoming larger, indicating a weaker discrete-continuum interference, as the two QPCs are moved apart.



Y. Yoon et al., PRB <u>79</u>, 121304 (2009).





Looking at the field dependence



Y. Yoon et al., PRL <u>99</u>, 136805 (2007).





Looking at the field dependence

• This peak splitting is interpreted as Zeeman splitting of a bound-state within the QPC.



Y. Yoon et al., PRL 99, 136805 (2007).



Is there a bound-state formed in a QPC?

 Bound-state formation in a QPC is consistent with recent g* measurements. Exchange effects and g* are highly sensitive to shape, size, etc in quantum dots.



A.M. Burke et al., Nano Lett. in press. doi: 10.1021/nl301566d





More recently...

• Work has focussed on interactions between bound-states in two adjacent QPCs.



Y. Yoon *et al.*, PRX <u>2</u>, 021003 (2012).





Towards spontaneous ordering of electrons







If electrons subject to exchange and correlation can reorganize to form bound-states, is there scope for larger organized electron structures?





The Wigner crystal

 In the low density limit, the potential energy dominates over the kinetic energy for a gas of electrons. This drives the electrons to form an ordered crystalline lattice to minimise the potential energy.



• Not only should this happen in 2D, but it can happen in 1D too. And in crystallizing, the electrons need to account for their exchange energy too...



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• The simplest model is a chain of electrons in a quantum wire with a transverse confining potential $V_{conf}(y) = m\Omega^2 y^2/2$, where Ω is the harmonic oscillator frequency.



• The Hamiltonian contains the usual terms (e.g., kinetic & potential energy due to confinement and electron-electron interaction) along with an exchange contribution described by the Heisenberg Hamiltonian:

$$H_{12} = \sum_{j} \left(J_1 S_j S_{j+1} + J_2 S_j S_{j+2} \right)$$

where J_1 and J_2 are exchange coupling parameters for the nearest neighbour and next-nearest neighbour spin interactions.





• At low density, the electrons form an ordered 1D lattice, but on increasing the density, a zig-zag lattice forms once the electron separation becomes less than a characteristic length scale for the 1D confinement $r_0 = (2e^2/\epsilon m\Omega^2)^{1/3}$.



• Defining a dimensionless density $v = nr_0$, where *n* is the 1D density in the quantum wire, the linear crystal is found to be stable for v < 0.78, with the zig-zag chain occurring for 0.78 < v < 1.75.

A.D. Klironomos et al., Europhys. Lett 74, 679 (2006).

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• The spin state of the system depends on the sign of the two exchange coupling parameters J_1 and J_2 (and the number of exchange terms included).



A.D. Klironomos et al., PRB 76, 075302 (2007).



• At higher density, structures with three or more rows can be obtained, with discrete transitions between phases with different numbers of chains.



• The parameters for the phase diagram are $\kappa = r_0/\lambda$, where λ is the screening length, and $n_e = lr_0/a$ where *l* is the number of chains and *a* is the separation between two adjacent particles in the same chain. r_0 has the same meaning as previously.

G. Piacente et al., PRB 69, 045324 (2004).





Numerical studies of electron ordering

• Güçlü *et al.* performed quantum Monte Carlo simulations to study a narrow 2D quantum ring with a constriction in it. The system is described by:

$$H = -\frac{1}{2}\sum_{i}^{N} \nabla_{i}^{2} + \frac{1}{2}\sum_{i}^{N} \omega^{2}(r_{i} - r_{0})^{2} + \sum_{i < j}^{N} \frac{1}{r_{ij}} + V_{g} \{ \tanh[s(\theta_{i} + \theta_{0})] - \tanh[s(\theta_{i} - \theta_{0})] \}$$

where the parabolicity ω controls the width of the ring, r_0 is its radius, V_g is the gate voltage controlling the constriction, and *s* and θ are the sharpness and length of the gate potential defining the constriction.



A.D. Güçlü et al., PRB 80, 201302 (2009).





Numerical studies of electron ordering



Abrupt barrier with flat plateau enhances localization and gap between liquid and crystal regions.

A.D. Güçlü et al., PRB 80, 201302 (2009).



Numerical studies of electron ordering

• Similar structures emerge from spin density functional theory.



E. Welander et al., PRB 82, 073307 (2010).



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• Studies performed using a top-gated QPC. The device is operated a little differently to a normal QPC. The side-gates are held fixed and the top-gate is swept.



• The strength of the 1D confinement is controlled by V_{sg} , as measured by $\Delta E_{n,n,+1}$

W.K. Hew, Ph.D. Thesis, Cambridge University (2009).





• A zig-zag phase should act like two channels, giving a first plateau at $2G_0$ not G_0 .



W.K. Hew et al., PRL <u>102</u>, 056804 (2009).



Unlike other plateaus, the weak-confinement $2G_0$ plateau appears to spin-split into more than two components.



W.K. Hew et al., PRL 102, 056804 (2009).





• Measurements with $B_{\parallel} = 7T$ (left) and 16T (right) reveal a G_0 plateau that crosses, and at the same time destroys, the $\frac{1}{2}G_0$ plateau, which recovers thereafter.



• This cannot occur in a non-interacting single wire, it is attributed to the bifurcation of a single channel wire in the strongly confined limit to a zig-zag configuration in the weakly-confined limit.

W.K. Hew et al., PRL 102, 056804 (2009).



To the edge of understanding



W.K. Hew et al., Physica E <u>42</u>, 1118 (2010).





To the edge of understanding



The zero-bias peak extends up to roughly $2G_0$, but most interestingly, it appears to split at lower *G*.

The physics behind this is an open question.

W.K. Hew *et al.*, Physica E <u>42</u>, 1118 (2010).



To the edge of understanding



The normal sourcedrain bias structure for the first plateau is duplicated.

This is currently not understood either.

L.W. Smith et al., PRB 80, 041306 (2009).



Throwing a cat amongst the pidgeons



• We may be conveniently forgetting something very important here...



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An alternate explanation

• It is worth noting that loss of the G_0 plateau can also arise from an attractive boundstate within a quantum wire.



J.H. Bardarson et al., PRB 70, 245308 (2004).





An alternate explanation

• The loss of the G_0 plateau is seen experimentally, without 'weak confinement', etc.



P.M. Wu et al., PRB 85, 085305 (2012).



The skeleton in the closet



- A common criticism levelled in studies of QPCs is one of disorder. It is often used to dismiss data (both one's own, and that of others).
- A common strategy to dodge the disorder attack is channel shifting by asymmetric biasing of the QPC gates. I want to finish with a scrutinizing look at this.



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An additional consideration -- Disorder



J.A. Nixon et al., PRB 43, 12638 (1991).

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The ballistic transport myth

• To give one example about the danger in ignoring disorder in mesoscopic devices, consider ballistic transport in quantum dots.

Advances in semiconductor fabrication have made it possible to study the electrical properties of two-dimensional, solidstate devices so small (~ 1 μ m) and cold (~ 0.05 K) that their length scales are much smaller than the mean free paths for impurity scattering of electrons². In this 'ballistic transport regime' the electrical resistance arises from the elastic scattering of the electrons from the sides of the microstructure, so the conductance properties of these small solid-state devices are strongly dependent on their shapes.

R.V. Jensen, Nature 373, 16 (1995).

The ballistic transport myth

• This line of thinking still holds today, across a wide range of mesoscopic device work.

"Therefore, it is

important to understand the consequences of nondiffusive electron dynamics on the electronic conductance or other transport properties. This question has been studied in much detail for semiconductor nanostructures in which the motion of electrons is ballistic rather than diffusive [1-4]. In such systems, disorder is negligible, and, consequently, all transport properties are determined by the shape of the sample, as in a billiard model.

Prusty & Schanz, PRL <u>96</u>, 130601 (2006).

We can see its not ballistic...

 Deflections at the sub-100nm length scale despite 'mean free paths' of >10µm due to small-angle scattering from ionized impurities.

M.P. Jura et al., Nat. Phys. <u>3</u>, 841 (2007).

K.E. Aidala et al., Nat. Phys. <u>3</u>, 464 (2007).

... and we can measure it too.

 Raising the temperature above 120K alters the ionized impurity potential, which in turn changes the interference. If the transport was really ballistic and determined only by the geometry, then this should not happen.

B.C. Scannell et al., PRB 85, 195319 (2012).

... and we can measure it too.

• If you remove the dopants, the conductance fluctuations become robust to room temperature thermal cycling... but that probably doesn't mean they're gone entirely.

A.M. See et al., PRL 108, 196807 (2012).

Reconsidering the past

• These new results force us to reconsider our notions of ballistic transport.

For example, the horizontal differences are no more significant than the vertical differences comparing data panels.

This can be explained by disorder rather than geometry dominating the transport (i.e., these 'ballistic' devices aren't really ballistic).

C.M. Marcus et al., PRL 69, 506 (1992); for more, see A.P. Micolich et al., doi: 10.1002/prop.201200081 (2012).

Back to QPCs

• To give just one example where this might matter for QPCs...

A QPC with an impurity doesn't get made into a clean QPC just by shifting the channel. The whole system is dirty by definition!

M.P. Jura et al., Nat. Phys. 3, 841 (2007).

Perhaps a little controversial ©, but...

Does indulging in pictures like:

- Given this, we really have to seriously ask ourselves whether 'elegant' pictures of simple potentials, clean electron distributions and nice ideas like 1D Wigner crystal zig-zag chains really make sense? They're useful, but do they explain reality?
- And if they do, how they survive the horrible mess of disorder in the experimental systems that we all work on is something in urgent need of understanding.

What are the key questions?

1. If we go back to just having a disorder potential like in Nixon and Davies, but properly accounting for exchange, correlation, etc., do we get 0.7?

In other words, how robust is 0.7 to disorder from a theoretical perspective?

- 2. Can more complex manifestations of Kondo explain some of the things we see in QPCs (e.g., strange zero-bias peak behaviour)? To what extent can disorder reliably produce such scenarios?
- 3. Is it really possible that a 1D Wigner crystal can survive and flow with disorder?

Thank you for listening

And best of luck if you decide to get involved in sorting out the mess that is 0.7...

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